



1A SBR[®] SUPER BARRIER RECTIFIER

Features

- Low Forward Voltage Drop
- Low Reverse Leakage
- Excellent High Temperature Stability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- Totally Lead- Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating).
 - Solderable per MIL-STD-202, Method 208 🕄
- Polarity: See Diagram
- Weight: 0.008 grams (Approximate)



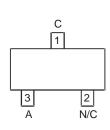


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Device Schematic

SOT-23

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Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
SBR160S23-7	SOT-23	3,000/Tape & Reel

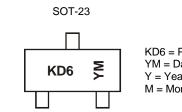
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



KD6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2010	20	11	2012	2013	201	4	2015	2016	20	017	2018
Code	Х	Y	,	Z	А	В		С	D		E	F
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

SBR is a registered trademark of Diodes Incorporated



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} Vrwm Vrm	60	V
Average Rectified Output Current	lo	900	mA
Average Peak Forward Current; D.C. = 50%	IFAV	1,600	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	15	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	500	mW
Typical Thermal Resistance Thermal Resistance Junction to Ambient Air (Note 5) Thermal Resistance Junction to Ambient Air (Note 6)	R _{θJA} R _{θJA}	300 250	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

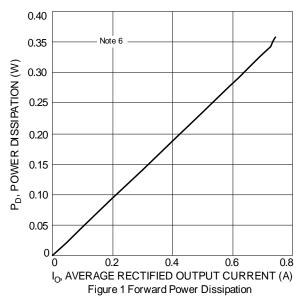
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V _R	60	-	-	V	I _R = 1mA
Forward Voltage (Per Diode)	V _F	-	- - - -	470 530 600 740	mV	I _F = 500mA I _F = 750mA I _F = 1000mA I _F = 1500mA
Leakage Current (Note 7)	I _R	-	-	100	μA	$V_R = 45V, T_J = +25^{\circ}C$
Total Capacitance	CT	-	19	-	pF	V _R = 25V, f = 1MHz
Reverse Recovery Time	t _{rr}	-	16	-	ns	$I_F = I_R = 10$ mA, IRR = 0.1 x I_R R _L = 100 Ω

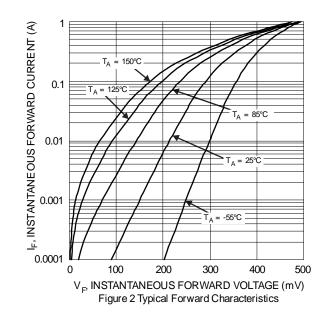
Notes:

5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com.

6. Part mounted on 1 inch sq. 2oz copper pad.

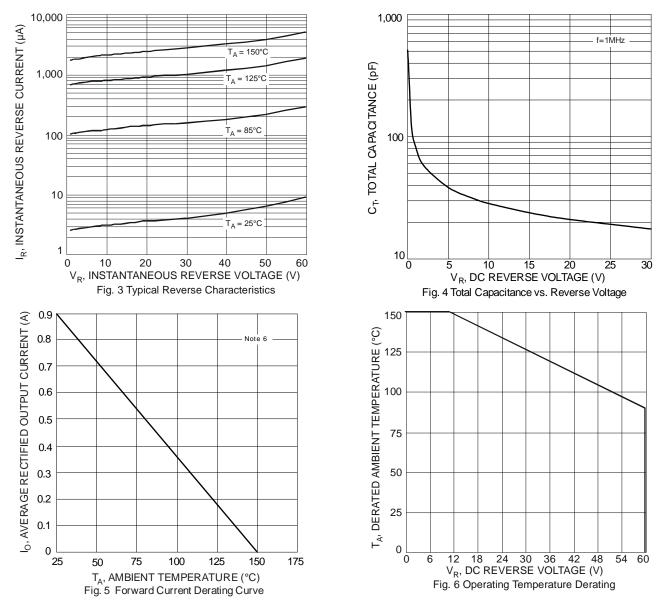
7. Short duration pulse test used to minimize self-heating effect.





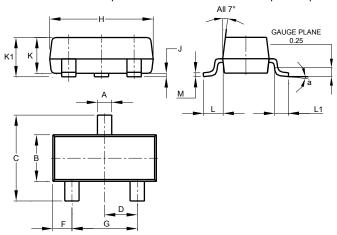


SBR160S23



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

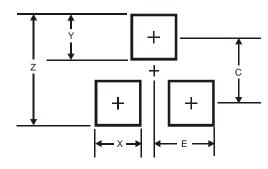


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
в	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
Σ	0.085	0.150	0.110			
а	8°					
All Dimensions in mm						



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

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